

Photocouplers Photorelay

TLP170D

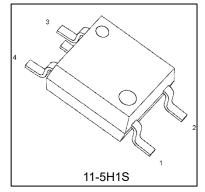
1. Description

The Toshiba TLP170D consists of an infrared emitting diode optically coupled to a photo-MOSFET in a 4-pin SOP package.

This photorelay requires 1 mA of LED current to turn it on. It is suitable for applications that need electrical power savings.

2. Applications

Mechanical relay replacements Security Equipment Measuring Instruments Factory Automation (FA) Private Branch Exchanges (PBXs)



Weight: 0.1 g (typ.)

3. Features

- Package: SOP (2.54SOP4) (Height 2.1 mm, pitch 2.54 mm)
- Normally opened (1-Form-A)
- OFF-state output terminal voltage: 200 V (min)
- Trigger LED current: 1 mA (max)
- ON-state current: 200 mA (max)
- ON-state resistance: 8Ω (max)
- Isolation voltage: 1500 V_{rms} (min)
- Safety standards
 - UL-recognized: UL 1577, File No.E67349
 - cUL-recognized: CSA Component Acceptance Service No.5A File No.E67349

Start of commercial production 2009-06



4. Pin Assignment

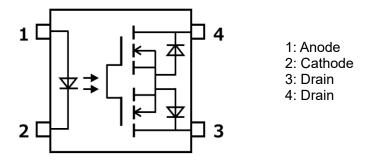


Figure 4.1 Pin Assignment

5. Internal Circuit

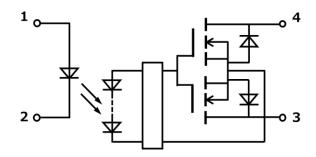


Figure 5.1 Internal Circuit



6. Absolute Maximum Ratings (Note)

(T_a = 25°C unless otherwise specified)

	Characteristics	Symbol	Note	Rating	Unit
LED	Input forward current	I _F		50	mA
	Input forward current derating (T _a ≥ 25 °C)	ΔI _F /ΔT _a		-0.5	mA/°C
	Input reverse voltage	V _R		5	V
	Pulse forward current (100 µs pulse, 100 pps)	IFP		1	Α
	Input power dissipation	PD		50	mW
	Input power dissipation derating (T _a ≥ 25 °C)	ΔP _D /ΔT _a		-0.5	mW/°C
	Junction temperature	Tj		125	°C
Detector	OFF-state output terminal voltage	Voff		200	V
	ON-state current	I _{ON}		200	mA
	ON-state current derating (T _a ≥ 25 °C)	ΔI _{ON} /ΔT _a		-2.0	mA/°C
	Output power dissipation	Po		300	mW
	Output power dissipation derating (T _a ≥ 25 °C)	ΔΡ _Ο /ΔΤ _a		-3.0	mW/°C
	Junction temperature	Tj		125	°C
Common	Storage temperature	T _{stg}		-55 to 125	°C
	Operating temperature	T _{opr}		-40 to 85	°C
	Lead soldering temperature (10 s)	T _{sol}		260	°C
	Isolation voltage (AC, 60 s, R.H. ≤ 60 %)	BVs	(Note 1)	1500	V _{rms}

Using continuously under heavy loads (e.g. the application of high temperature / current / voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc)

Note 1: This device is considered as a two-terminal device: Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together.

7. Recommended Operating Conditions (Note)

Characteristics	Symbol	Note	Min	Тур.	Max	Unit
Supply voltage	V_{DD}		_	_	160	V
Input forward current	l _F		_	2	25	mA
ON-state current	Ion		_	_	160	mA
Operating temperature	T _{opr}		-20	_	65	°C

The recommended operating conditions are given as a design guide necessary to obtain the Note: intended performance of the device. Each parameter is an independent value. When creating a system design using this device, the electrical characteristics specified in this data sheet should also be considered.



8. Electrical Characteristics

(T_a = 25°C unless otherwise specified)

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	Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
LED	Input forward voltage	VF		I _F = 10 mA	1.0	1.15	1.3	V
	Input reverse current	I _R		V _R = 5 V	_	_	10	μA
	Input capacitance	Ct		V = 0 V, f =1 MHz	_	30	_	pF
Detector	OFF-state current	I _{OFF}		V _{OFF} = 200 V	_	1	1000	nA
	Output capacitance	C _{OFF}		V = 0 V, f =1 MHz	_	90	_	pF

9. Coupled Electrical Characteristics

(T_a = 25°C unless otherwise specified)

		,				,	
Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}		I _{ON} = 200 mA		0.4	1	mA
Return LED current	I _{FC}		I _{OFF} = 100 μA	0.1	_	_	mA
ON-state resistance	Ron		I _{ON} = 200 mA, I _F = 2 mA	_	5	8	Ω

10. Isolation Characteristics

(T_a = 25°C unless otherwise specified)

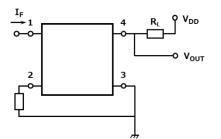
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Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Total capacitance (input to output)	Cs	(Note 1)	V _S = 0 V, f = 1 MHz	_	0.8	_	pF
Isolation resistance	Rs	(Note 1)	V _S = 500 V, R.H. ≤ 60 %	5×10 ¹⁰	10 ¹⁴	_	Ω
Isolation voltage	BVs	(Note 1)	AC, 60 s	1500	_	_	V _{rms}

Note 1: This device is considered as a two-terminal device: Pins 1 and 2 are shorted together, and pins 3 and 4 are shorted together.

11. Switching Characteristics

(T_a = 25°C unless otherwise specified)

			(1a - 25	C unites	3 Olliel W	ise speci	ileu)
Characteristics	Symbol	Note	Test Condition	Min	Тур.	Max	Unit
Turn-on time	ton		See Figure 11.1 $R_L = 200 \Omega$, $V_{DD} = 20 V$, $I_F = 2 mA$	_	3.0	8.0	ms
Turn-on time	ton		See Figure 11.1 $R_L = 200 \Omega$, $V_{DD} = 20 V$, $I_F = 5 \text{ mA}$	_	_	5.0	
Turn-off time	toff		See Figure 11.1 $R_L = 200 \Omega$, $V_{DD} = 20 V$, $I_F = 2 \text{ mA}$	_	0.6	3.0	



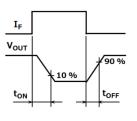


Figure 11.1 Switching Time Test Circuit and Waveform



12. Characteristics Curves and Circuit Connections (Note)

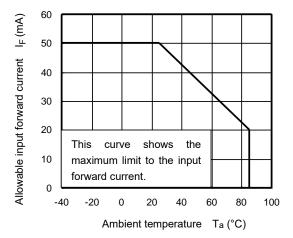
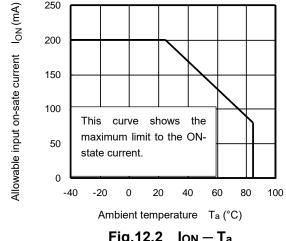


Fig.12.1 IF - Ta



250

Fig.12.2 ION - Ta

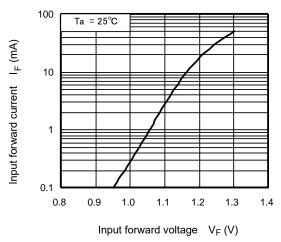


Fig.12.3 If - VF

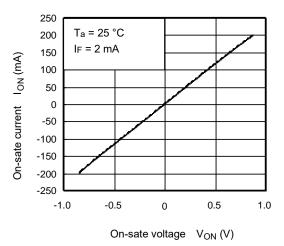


Fig.12.4 Ion — Von

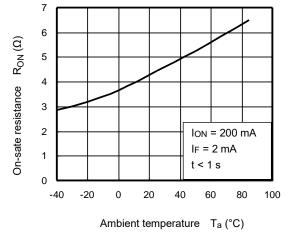


Fig.12.5 $R_{ON} - T_a$

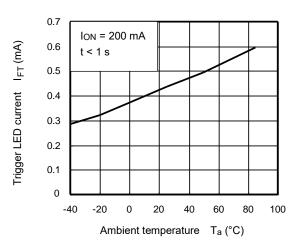


Fig.12.6 $I_{FT} - T_a$

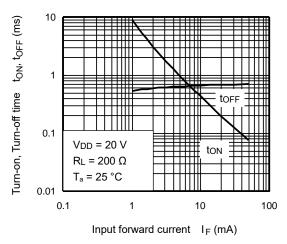


Fig.12.7 t_{ON} , $t_{OFF} - I_F$

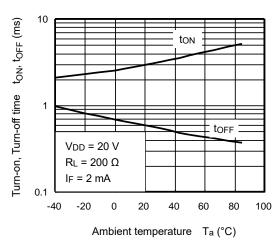


Fig.12.8 t_{ON} , $t_{OFF} - T_a$

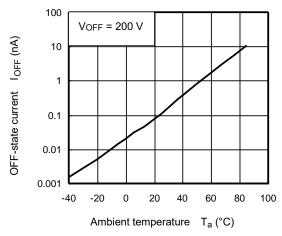


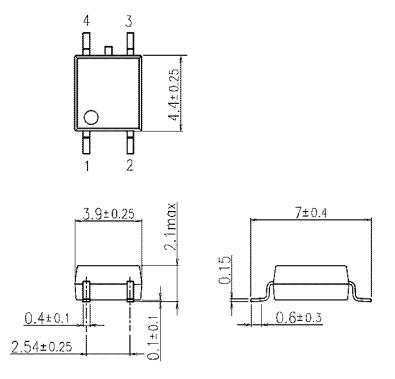
Fig.12.9 $IOFF - T_a$

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



13. Package Dimensions

11-5H1S Unit: mm



Weight: 0.1 g (typ.)

Fig. 13.1 Package Dimensions



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